NSN 5962-00-530-4660

Memory Microcircuit - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5962-00-530-4660

Body Length:

Between 0.735 inches and 0.830 inches

Body Width:

Between 0.245 inches and 0.295 inches

Body Height:

Between 0.055 inches and 0.125 inches

Maximum Power Dissipation Rating:

700.0 milliwatts

Operating Tempurature Range:

-55.0/+85.0 degrees celsius

Storage Tempurature Range:

-62.0/+125.0 degrees celsius

Features Provided:

Monolithic and hermetically sealed and low power and 3-state output and positive outputs

Inclosure Material:

Ceramic and glass

Inclosure Configuration:

Dual-in-line

Output Logic Form:

P-type metal oxide-semiconductor logic

Input Circuit Pattern:

11 input

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

20.0 volts power source

Memory Device Type:

Rom

Memory Capacity:

Unknown

Test Data Document:

94117-310117 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

Terminal Type And Quantity:

16 printed circuit

Shelf Life:

N/a

Unit Of Measure:

--

Demilitarization:

Yes - demil/mli

Fiig:

A458a0